

# MN4030B/S, MN4070B/S

## Quad Exclusive-OR Gate

### ■ Outline

The MN4030B/S and the MN4070B/S are exclusive OR gates respectively having four built-in circuits in one chip. the inverter buffer added to the respective gate output improves the input/output characteristic and minimizes the propagation delay time fluctuation caused by the load capacity increase.

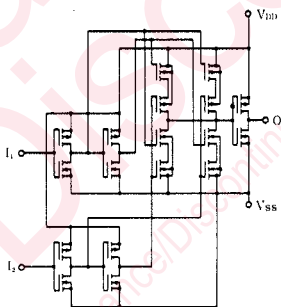
These exclusive OR gates of low power consumption with high noise immunity are applicable to digital comparators, parity circuits, etc.

The MN4030B/S and the MN4070B/S are equivalent to Motorola's MC14070B and RCA's CD4070B.

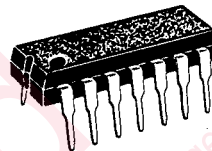
### ■ Truth Table

$I_1$	$I_2$	$O_1$
L	L	L
H	L	H
L	H	H
H	H	L

### ■ Schematic Diagram



P-1



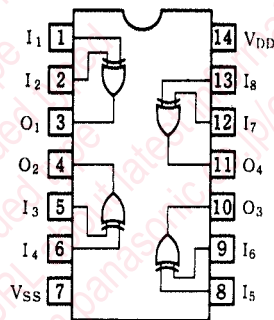
14-pin plastic DIL package

P-2



14-pin PANAFLAT package (SO-14D)

Pin Configuration



### ■ Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Rating	Unit
Supply voltage	$V_{DD}$	-0.5~+18	V
Input voltage	$V_I$	-0.5~ $V_{DD}+0.5^*$	V
Output pin voltage	$V_O$	-0.5~ $V_{DD}+0.5^*$	V
Peak input · output pin current	$\pm I_I$	max. 10	mA
Power dissipation (per package)	$T_a = -40 \sim +60^\circ\text{C}$	max. 400	mW
	$T_a = +60 \sim +80^\circ\text{C}$	Decrease to 200mW at the rate of 8mW/°C	
Power dissipation (per output pin)	$P_D$	max. 100	mW
Operating ambient temperature	$T_{opr}$	-40~+85	°C
Storage temperature	$T_{stg}$	-65~+150	°C

\*  $V_{DD}+0.5V$  should be lower than 18V.

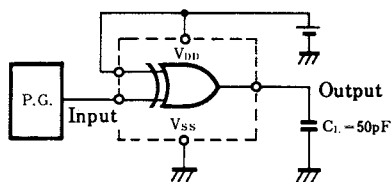
■ DC Characteristics (V<sub>SS</sub>=0V)

Item	V <sub>DD</sub> (V)	Symbol	Condition	Ta=-40°C		Ta=25°C		Ta=85°C		Unit
				min.	max.	min.	max.	min.	max.	
Static supply current	5	I <sub>DD</sub>	V <sub>I</sub> =V <sub>SS</sub> or V <sub>DD</sub>	—	1	—	1	—	7.5	μA
	10			—	2	—	2	—	15	
	15			—	4	—	4	—	30	
Output voltage low level	5	V <sub>OL</sub>	V <sub>I</sub> =V <sub>SS</sub> or V <sub>DD</sub>  I <sub>O</sub>  <1μA	—	0.05	—	0.05	—	0.05	V
	10			—	0.05	—	0.05	—	0.05	
	15			—	0.05	—	0.05	—	0.05	
Output voltage high level	5	V <sub>OH</sub>	V <sub>I</sub> =V <sub>SS</sub> or V <sub>DD</sub>  I <sub>O</sub>  <1μA	4.95	—	4.95	—	4.95	—	V
	10			9.95	—	9.95	—	9.95	—	
	15			14.95	—	14.95	—	14.95	—	
Input voltage low level	5	V <sub>IL</sub>	I <sub>O</sub>  <1μA V <sub>O</sub> =0.5V or 4.5V	—	1.5	—	1.5	—	1.5	V
	10			—	3	—	3	—	3	
	15			—	4	—	4	—	4	
Input voltage high level	5	V <sub>IH</sub>	I <sub>O</sub>  <1μA V <sub>O</sub> =0.5V or 4.5V	3.5	—	3.5	—	3.5	—	V
	10			7	—	7	—	7	—	
	15			11	—	11	—	11	—	
Output current low level	5	I <sub>OL</sub>	V <sub>O</sub> =0.4V, V <sub>I</sub> =0 or 5V V <sub>O</sub> =0.5V, V <sub>I</sub> =0 or 10V V <sub>O</sub> =1.5V, V <sub>I</sub> =0 or 15V	0.52	—	0.44	—	0.36	—	mA
	10			1.3	—	1.1	—	0.9	—	
	15			3.6	—	3	—	2.4	—	
Output current high level	5	-I <sub>OH</sub>	V <sub>O</sub> =4.6V, V <sub>I</sub> =0 or 5V V <sub>O</sub> =9.5V, V <sub>I</sub> =0 or 10V V <sub>O</sub> =13.5V, V <sub>I</sub> =0 or 15V	0.52	—	0.44	—	0.36	—	mA
	10			1.3	—	1.1	—	0.9	—	
	15			3.6	—	3	—	2.4	—	
Output current high level	5	-I <sub>OH</sub>	V <sub>O</sub> =2.5V, V <sub>I</sub> =0 or 5V	1.7	—	1.4	—	1.1	—	mA
Input leakage current	15	±I <sub>I</sub>	V <sub>I</sub> =0 or 15V	—	0.3	—	0.3	—	1	μA

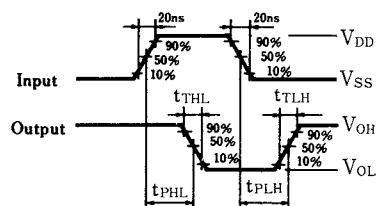
■ Switching Characteristics (Ta=25°C, V<sub>SS</sub>=0V, C<sub>L</sub>=50pF)

Item	V <sub>DD</sub> (V)	Symbol	min.	typ.	max.	Unit
Output rise time	5	t <sub>TLH</sub>	—	60	180	ns
	10		—	30	90	
	15		—	20	60	
Output fall time	5	t <sub>THL</sub>	—	60	180	ns
	10		—	30	90	
	15		—	20	60	
Propagation time	5	t <sub>PLH</sub>	—	75	225	ns
	10		—	30	90	
	15		—	25	75	
Propagation time	5	t <sub>PHL</sub>	—	85	255	ns
	10		—	35	105	
	15		—	30	90	
Input capacitance		C <sub>I</sub>	—	—	7.5	pF

1. Switching time measuring circuit



2. Switching waveforms



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